NSN 5961-01-148-6857

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View Online at https://aerobasegroup.com/nsn/5961-01-148-6857

Inclosure Material:
Metal
Overall Length:
1.573 inches
Terminal Length:
0.312 inches
Overall Height:
Between 0.250 inches and 0.450 inches
Overall Width:
1.050 inches
End Application:
5865-01-109-1701
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal and unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
25.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
Between 10.00 amperes source cutoff current and 25.00 amperes source cutoff current
Power Rating Per Characteristic:
200.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
1 case and 2 pin
Specification Data:
80131-release6390 professional/industrial association specification
Shelf Life:
N/o

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Demilitarization:

No

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